Terahertz Spectroscopy of CdSe Quantum Dots

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What is a quantum dot?



- Nanocrystals
- 2-10 nm diameter
- semiconductors

What is a quantum dot?



Exciton Bohr Radius Discrete electron energy levels Quantum confinement

Motivation

- Semiconducting nanocrystals are significant due to; strong size dependent optical properties (quantum confinement)
- applications solar cells



Terahertz gap



1 THz = 300 μ m = 33 cm⁻¹ = 4.1 meV



Terahertz Signal



To obtain the response of the sample to the THz radiation 2 measurements are made

THz electric field transmitted through the empty cell
THz electric field transmitted through the sample cell

Terahertz signal



Doping

- Intentionally adding impurities to change electrical and optical properties
- Add free electrons to conduction band or free holes in valence band
- Tin and Indium dopants

Free carrier Absorption in Quantum Dots



Purification and sample preparation of quantum dots









Experimental procedure & Data analysis



No Kramer-Kronig analysis!!!

Changes upon charging large quantum dot: Intrinsic Imaginary Dielectric constant

The frequency dependent complex dielectric constants determined by experimentally obtained

• Frequency dependent absorbance and refractive index.

The complex dielectric constant = $(n_r(i) + in_i(i))^2$



•For the charged samples Frohlich Band diminishes: A broader and weaker band appears

•The reason of this is the presence of coupled plasmon-phonon modes

Results



- Surface phonon
- Shift of resonance of tin doped
- Agreement with charged QDs

